





7, Autogennaya Str., Kharkov, 61099, Ukraine. Phone: (+38-057) 728-1244, 728-1241. Fax: (+38-057) 728-1243, (+38-0572) 946-830 E-mail: market@yuzhcable.com.ua

АПвЭгПу(к)-10 3x150 ТУ У 31.3-00214534-017-2003

Three core power cables with aluminium conductors, XLPE-insulated, core-filled with bundles, with reinforced outer sheath of polyethylene

Technical cable requirements correspond to IEC 60502-2

Cables are used for laying:

- in soil (trenches)
- · on difficult route sections, according to the unique specification
- · in the air, including cable structures, if provided the additional fire protection

It is possible to manufacture cables with extruded semiconductor layer along outer sheath.

Order entry example:

АПвЭгПу(к)-П-10 3x150/25 ТУ У 31.3-00214534-017-2003

An extruded semiconductor layer along outer sheath ensures the correct testing of cable line with sections of underground laying in polymer pipes.

It is possible to manufacture cables with an integrated fiber-optic module.

Order entry example:

АПвЭгПу(к)-10 3x150/25 (ОМ) ТУ У 31.3-00214534-017-2003

In conjunction with the DTS system, the integrated fiber-optic module can act as a distributed cable line temperature sensor.

It is possible to manufacture cable with sealed conductors.

Order entry example:

АПвЭгПу(к)-10 3х150/25 (г) ТУ У 31.3-00214534-017-2003







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TECHNICAL SPECIFICATIONS

Rated voltage	kV	10
Maximum voltage	kV	12
Number and rated area of conductors	mm²	3 x 150
Insulation thikness	mm	3.4
Minimum screen cross-section	mm²	25
Permissible short circuit current across the screen of	kA	5.1
minimum cross-section		
Maximum permissible short-circuit current in core	kA	14.2
Permissible continious current rating *		
by aerial laying	Α	309
• by burial	Α	260
Partial discharge factor for rated voltage, not more than	рС	6
Maximum permissible conductor temperature		
Continious	°C	+90
in emergency operation	°C	+130
• at short circuit	°C	+250
Operating temperature range	°C	-60 +50
Minimum bending radius by laying	mm	1008
Rated outer diameter of the cable (for reference) **	mm	63
Cable weight (approximate)	kg/km	3290
Rated factory cable length and gross weight of the delivery	m, t	# 22УД-60: 450 • 2.4
on the drums ***		# 25УД-90: 771 • 4.1

Notes:

When ordering it is neccesary to agree the factory length of the product with the manufacturer

^{*} Long permissible current loads are calculated for the following conditions: conductor temperature 90 °C, air temperature 30 °C, soil temperature 20 °C, load factor 1.0, thermal resistivity of soil 1.5 °K • m/W, laying depth in the ground 0.8 m, shields are grounded at both ends of the line

^{**} The external diameter may differ from the rated up to \pm 10 %

^{***} Отклонение фактической массы брутто от указанного значения может составлять \pm 7 %



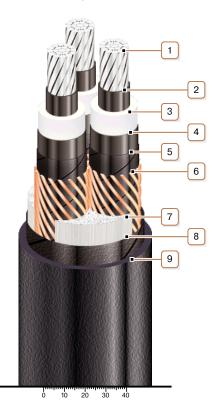




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CONSTRUCTION

- 1. Aluminium multiwire compacted conductor
- It is possible to manufacture cable with a single-wire conductor
- · It is possible to manufacture cable with sealed conductors.
- 2. Inner extruded semiconducting layer
- 3. XLPE insulation
- 4. Outer extruded semiconducting layer
- 5. Lapping layer of semiconductive swellable tape
- 6. Copper screen
- 7. Interstitial filler with polypropylene bundles
- 8. Lapping layer of semiconductive tape
- 9. Strengthened polyethylene outer sheath

Note: It is possible to manufacture cable with extruded semiconductor layer along outer sheath

Note: Conductor twisting is not illustrated